# G iant Extrinsic Spin Hall E ect due to Rare-Earth Impurities

T.Tanaka and H.Kontani

D epartm ent of P hysics, N agoya U niversity, Furo-cho, N agoya 464-8602, Japan.

E-mail: takuro@slab.phys.nagoya-u.ac.jp

A bstract. We investigate the extrinsic spin Halle ect in the electron gas model due to magnetic in purities, by focusing on Ce- and Yb-in purities. In the dilute limit, the skew scattering term dominates the side jump term. For Ce-in purities, the spin Hall angle  $_{\rm SH}$  due to skew scattering is given by 8  $_2$ =7, where  $_2$  (1) is the phase shift for d (l= 2) partial wave. Since  $_{\rm SH}$  reaches O (10<sup>-1</sup>) if  $_2$  > 0.03, considerably large spin Halle ect is expected to emerge in metals with rare-earth in purities. The present study provides the highly ecient way to generate a spin current.

## 1. Introduction

The spin Hall e ect (SHE) has been attracting a great deal of interest due to its fundam ental as well as technological in portance. The intrinsic SHE originates from the Berry phase of the multiband B loch function, so that the spin Hall conductivity (SHC) takes a material-speci c value that is independent of in purity scattering in the low resistivity regime [1, 2]. In transition m etals, the intrinsic SHC takes a considerably large value  $\beta$ , 4], because of the \e ective A haronov-Bohm (AB) phase" induced by d-orbital degrees of freedom and the atom ic spin-orbit interaction (SO I) [5, 6, 7, 8]. Intrinsic SHE in Sr<sub>2</sub>RuO<sub>4</sub> had been calculated in ref. [5] based on the t<sub>2g</sub> tight-binding m odel. By the sam em echanism, SHE in transition m etals had been studied based on the realistic multiorbital tight-binding m odel in ref. [7] and the rst-principles calculations [9]. The obtained SHCs agree well with recent experim ental observations, in both the magnitude and sign [8].

In addition to the intrinsic mechanism, SHE is also induced by impurity scattering with the aid of SO I; this phenomenon is known as the extrinsic SHE [10, 11, 12]. It consists of a skew scattering term ( $_{SH}^{ss}$  /  $^{1}$ ) and a side jump term ( $_{SH}^{sj}$  /  $^{0}$ ); This fact suggests that considerable large SHC can be realized due to the skew scattering term in the very low resistivity metals, beyond the material-speci c intrinsic SHC. For this reason, study of the extrinsic SHE is signi cant for realizing excellent spintronics device to produce or detect the spin current.

The extrinsic SHE due to nonm agnetic in purities or vacancies had been studied in refs. [10, 11, 12], by developing the theory of the extrinsic anom alous Halle ect (AHE) [13, 14, 15]. The obtained SHC is, however, very sm all unless the enhancement factor for the SO I due to the multiband e ect is taken into consideration. For this reason, it is not easy to estimate the magnitudes of  $\frac{ss}{SH}$  and  $\frac{sj}{SH}$  due to nonmagnetic impurities. In transition metals, there is no apparent experimental evidence for a large extrinsic SHE due to natural random ness.

D ilute magnetic in purities such as Fe and Ce have been found to induce a large extrinsic AHE in simple metals [17, 16]. The Hall angles in AuFe [17] and rare-earth doped metals [16] reach 0.01 0.001 under high magnetic elds. Since the SHE has a similar mechanism to that of the AHE, one might expect that a giant SHE can be realized by magnetic in purities. However, theoretical analysis of the extrinsic SHE in a sim ple s-electron metal due to magnetic in purities has not been performed previously.

In this paper, we study the extrinsic SHE based on a single-in purity Anderson model for Ce and Yb atoms, both of which are typical magnetic in purities. Nonperturbative e ect of the large SO I for f-electrons ( 3000 K) is correctly accounted for. Due to skew scattering, the obtained spin Hall angle  $_{SH} = \frac{j_x^s}{j_y^c} \frac{2jej}{h}$ , which is the ratio between the transverse spin Hall current and the longitudinal electric current, exceeds 0:1 for  $_2 > 0:03$ , where  $_2$  ( 1) is the phase shift for d (l = 2) partial wave; It is more than 10 times greater than that in nonmagnetic metals such as Pt [4]. Since

the spin H all angle represents the e-ciency of the creating spin current, giant spin H all current is expected to emerge in simplem etals by introducing dilutem agnetic in purities. Moreover, the extrinsic SHC can take a large value well above the K ondo temperature  $T_K$ , in contrast to the anom alous H all conductivity (A H C). The origin of the giant SHE is found to be the large SO I and angular momentum in the rare-earth in purities, which had not been treated appropriately in previous studies of the extrinsic SHE.

# 2. M odel and H am iltonian

In this study, we use the single-impurity Anderson model for Ce and Yb atoms. In a  $Ce^{3+}$  ion with a  $4f^1$  conguration, the J = 7=2 level is about 3000 K higher than the J = 5=2 level due to the strong atom ic SO I [18]. Therefore, we consider only J = 5=2 states for the Ce-impurity. In the same way, we consider only J = 7=2 states in Yb<sup>3+</sup> ion with  $4f^{13}$  conguration. Here, we introduce the following single-impurity Anderson model for Ce=Yb atoms with both d- and f-orbitals [16]:

$$H = {}^{X} {}^{w}_{k} c_{k}^{y} c_{k} + {}^{X} {}^{E} {}^{d} d_{m}^{y} d_{m} + {}^{X} {}^{E} {}^{f} f_{M}^{y} f_{M}$$

$$+ {}^{k}_{X} {}^{n} {}^{v} c_{k}^{y} d_{m} + h \mathfrak{x} : + {}^{X} {}^{n} {}^{k} {}^{m} c_{k}^{y} f_{M} + h \mathfrak{x} :$$

$$+ {}^{U^{f}} {}^{Z} {}^{w} {}^{m} {}^{n} {}^{m} {}^{n} {}^{f} {}^{n} {}^{f} {}^{j} {}^{;}$$

$$(1)$$

where we have employed the electron (hole) picture for the Ce (Yb) in purity.  $c_k^y$  is the creation operator of a conduction electron with spin = 1.  $f_M^y$  is the creation operator of a f-electron with total angular momentum J = 5=2 (7=2) and z-component M (J M J) for  $C^3$ th (Yb<sup>3+</sup>).  $d_m^y$  is the creation operator of a d-electron with angular momentum m (2 m 2)19]. " $_k = k^2=2m$  is the energy for the conduction-electrons, and E<sup>f</sup> (E<sup>d</sup>) is the localized f (d)-level energy.  $V_{kM}^f$  and  $V_{km}^d$  are the mixing potentials, which are given by

$$V_{kM}^{f} = \stackrel{p}{4} V_{f} \stackrel{x}{a}_{m}^{M} Y_{3}^{m} (\hat{k}); \qquad (2)$$

$$V_{km}^{d} = 4 V_{d}Y_{2}^{m} (\hat{k});$$
 (3)

where  $a_m^M$  is the C lebsch-G ordan (C-G) coe cient and  $Y_1^m$  ( $\hat{k}$ ) is the spherical harm onic function. We will show that the phase factor in  $Y_1^m$  ( $\hat{k}$ ) and  $a_m^M$  are indispensable to realize the SHE. For J = 5=2,  $a_m^M$  =  $f(7=2 \ M) = 7g^{1=2} \ m, M = 2$  [20, 21]. Note that the SO I was neglected in the study of the AHE in ref. [16]. In the present study, we neglect the crystalline electric eld of the f-orbitals, since it is sm all due to the sm all radius of the f-orbital wave function [16]. We put h = 1 hereafter.

To discuss the scattering problem, it is useful to derive an e ective Ham iltonian for the conduction electrons by integrating out the f and d electrons in eq. (1). The obtained Ham iltonian is given by [16]

$$H_{c} = \sum_{k}^{X} H_{c} = \sum_{k}^{Y} G_{k} + \sum_{k,k^{0};}^{X} J_{k,k^{0}}^{d} G_{k}^{Y} G_{k^{0}} + \sum_{kk^{0};}^{X} J_{k,k^{0}}^{f} G_{k}^{Y} G_{k^{0}} G_{k}^{Y} G_{k^{0}} G_{k^{0}}^{Y} G_{k^{0}} G_{k^{0}} G_{k^{0}}^{Y} G_{k^{0}} G_{k^$$

where

$$J_{k\,jk^{0}}^{d} = \frac{1}{\frac{E^{d}}{K}} V_{km}^{d} V_{k^{0}m}^{d}$$
$$= 4 J_{d} Y_{2}^{m} (\hat{k}) Y_{2}^{m} (\hat{k}^{0})^{i} ; \qquad (5)$$

$$J_{k}^{f}{}_{;k^{0}}{}_{,k^{0}}{}_{,0}^{\circ} = \frac{1}{\underbrace{E^{f}}_{M}}^{X} V_{kM}^{f} V_{k^{0}M}^{f}{}_{,0}^{\circ}$$
$$= 4 J_{f}^{X} a_{m}^{M} a_{m}^{M} a_{m^{0}}^{M} Y_{3}^{m} (\hat{k}) Y_{3}^{m^{0}} (\hat{k}^{0})^{i}; \qquad (6)$$

and  $J_d = j_d j_f^2 = (E^d)$  and  $J_f = j_f j_f^2 = (E^f)$ . Here,  $E^f = E^f + Re^f$ ; f is the f-electron self-energy due to the Coulomb interaction U<sup>f</sup> [20]. According to the scaling theory [22],  $E^f$  approaches the Ferm i level as the temperature decreases due to the K ondo e ect:  $j_f j$  is strongly enhanced near  $T_K$ , and below  $T_K$ ,  $J_f N (0) = 1$  due to strong resonant scattering, where N (0) = m  $k_F = 2^{-2}$  is the density of state of the conduction band per spin. We also assume that  $J_d N (0) (= \tan_2 = ) = 1$  since  $j = E^d j = 0$  (1eV) [6].

## 3. Calculations

### 3.1. T-m atrix due to c-f Resonant Scattering

In this section, we study the scattering problem . In the both models given by eq. (1) and eq. (4), the T-m atrix due to the c-f resonant scattering is equivalent; it is given by

$$T_{k}^{f}_{;k^{0}} = J_{k}^{f}_{;k^{0}} + \frac{1}{N} \sum_{k_{1}; 1}^{X} J_{k}^{f}_{;k_{1}} G_{k_{1}}^{0} T_{k_{1}}^{f}_{;k^{0}};$$
(7)

where its diagram matic expression is shown in Fig. 1 (a), N is the number of k-points, and  $G_k^0 = (" "_k)^1$ . We note that the term containing both  $J_k^f_{k,k^0}$  and  $J_{k,k^0}^d$  given in Fig. 1 (b) vanishes identically due to the orthogonality of spherical harm onic functions. The solution of eq. (7) for  $k = k^0$  and  $= {}^0$  is simply given by

$$T_{k}^{f}{}_{,k} (") = 3J_{f} \frac{1}{1 - J_{f}g(")};$$
(8)

$$f_{f} = n_{im p} \operatorname{Im} T_{k,k}^{fR} (0) = 3n_{im p} \frac{N (0) J_{f}^{2}}{1 + (N (0) J_{f})^{2}};$$
(9)

where  $n_{imp}$  is the impurity concentration. Note that eq. (9) is exact for  $n_{imp}$  1.

#### 3.2. Skew Scattering Term

In this section, we study the skew scattering term using linear response theory. Initially, we consider the case N  $(0)J_f$  1 and  $J_d$   $J_f$ , where the Born approximation is valid.

Giant Extrinsic Spin Hall E ect due to Rare-Earth Impurities



Figure 1. (a) Diagram matic expression for the T-matrix due to c-f resonant scattering. (b) The diagram that vanishes after  $k_1$  -sum mation.

In analogy to [15, 16], the skew scattering term is given by

$$S_{\rm SH}^{\rm SS} = \frac{e}{2} n_{\rm im \, p} \frac{1}{N^2} \frac{X}{k_{;k^0}} \frac{e_{k_k}^{\rm m} e_{k_k}^{\rm m}}{2 \frac{e_{k_k}^{\rm m}}{e_{k_k}^{\rm m}} \frac{e_{k_k}^{\rm m}}{e_{k_k}^{$$

where e (e > 0) is the electron charge. Its diagram matic expression is shown in Fig. 2 (a). Here,

$$T_{k}^{f(2)R}_{k'k^{0}}(0) = \frac{1}{N} \sum_{k_{1}; 1}^{X} J_{k'k_{1}}^{f} G_{k_{1}}^{R}(0) J_{k_{1}}^{f}_{1'k^{0}}$$
$$= g^{R}(0) J_{k'k^{0}}^{f} J_{f}$$
(11)

is the second order term of the T-matrix; the second reaction in  $J_{k}^{f}{}_{;k^{0}}$  does not contribute to  $_{SH}^{SS}$  up to the second reaction in  $J_{d}$  [16]. Note that any diagram that contains the part shown in Fig. 1 (b) vanishes identically. The retarded G reen function is given by  $G_{k}^{R}(0) = (m_{k}^{R} + i)^{1}$ , where represents the quasiparticle damping rate. Here, we put

$$= _{f} + _{0};$$
 (12)

where  $_0$  is the damping rate due to nonmagnetic scattering, such as c-d scattering ( $_d = 5 n_{imp}N(0)J_d^2$ ) and the scattering due to disorders. The charge current is given by  $j^c = e@!_k = @k$ , where = x;y. The spin current is then given by  $j^s = (=2)@!_k = @k$ . First, we consider the angular integration in eq. (10), which is given by

$$X = \frac{D}{2} J_{k}^{f}{}_{,k^{0}} J_{k^{0};k}^{d} f(\hat{k};\hat{k}^{0})^{E}; \qquad (13)$$



F igure 2. D iagram m atic expressions for SHC induced by skew scattering (a) within the lowest order (extended B orn approximation) contribution, and (b) in the T-m atrix approximation with full order diagram s.

where  $f(\hat{k};\hat{k}^0) = \frac{m^2}{k^2} \frac{\partial (\mathbf{k}_k)}{\partial (\mathbf{k}_y)} = \sin_k \cos_k \sin_{k^0} \sin_{k^0} \sin_{k^0}$ , and h denotes the average over the Ferm i level, which is de ned as  $A(\hat{k}_1; \hat{k}_n); = \frac{E}{2} = \frac{Z}{4} \frac{d_{k_1} - d_{k_n}}{(4-1)^n} A(\hat{k}_1 + \hat{k}_n) A(\hat{k}_n) A(\hat{k$ 

$$eq:(13) = i\frac{4}{7}J_dJ_f;$$

Using the relations  $\mathbf{j} \mathbf{G}_{k}^{R}(0) \mathbf{j}^{2} - (\mathbf{k}_{k}^{R})$  for small , and  $\frac{1}{N} \mathbf{G}_{k_{1}}^{R} \mathbf{G}_{k_{1}}^{R}(0) = \mathbf{g}^{R}(0) = \mathbf{i} \mathbf{N}(0)$ , eq. (10) is transformed into

$$\sum_{\text{SH}}^{\text{SS}} = \frac{e}{2} \frac{4}{7} n_{\text{im p}} J_{\text{d}} J_{\text{f}}^{2} N \quad (0)$$

$$\sum_{\substack{k,k^{0} \ k \neq 0}}^{X} \frac{e_{k}^{0}}{e_{k}} \frac{e_{k}^{0}}{e_{k}^{0}} \frac{1}{2} \quad (k) \quad (k) \quad (k) \quad (14)$$

Since  $f = 3 n_{imp} N$  (0) $J_f^2$  in the Born approximation,  $S_{SH}^{SS}$  is given by

$$_{\rm SH}^{\rm ss} = -\frac{e}{2} \frac{1}{21^{-2}} J_{\rm d} k_{\rm F}^4 - \frac{f}{2} :$$
 (15)

Now, we derive the skew scattering term using the T-m atrix approximation, which gives the exact result for  $n_{imp}$  1. In this case,  $T_{k}^{f(2)R}_{,k^0}$  (0) in eq. (10) is replaced with the full T-m atrix  $T_{k}^{fR}_{,k^0}$  (0) =  $T_{k}^{f(2)R}_{,k^0}$  (0) 1  $g^{R}(0)J_{f}^{-1}$ , where the rst order term in  $J_{k}^{f}_{,k^0}$  has been dropped. The diagram matic expression for  $S_{H}^{ss}$  is shown in Fig. 2 (b). The angular integration in the T-m atrix approximation can be performed as

$$\operatorname{Re}^{X} = \frac{1}{2} \operatorname{T}_{k,k^{0}}^{fR} (0) \operatorname{J}_{k^{0};k}^{d} f(\hat{k};\hat{k}^{0})^{E} = \frac{4}{7} \frac{\operatorname{J}_{d} \operatorname{J}_{f}^{2} N(0)}{1 + (N(0) \operatorname{J}_{f})^{2}} :$$
(16)

Thus,  $_{SH}^{ss}$  in the T-m atix approximation is given by  $(1 + (N(0)J_f)^2)^{-1}$  times eq. (14). Therefore, the expression for the skew scattering term in eq. (15) is valid beyond the Born approximation, by considering  $_f$  given by eq. (9).

Here, we discuss the temperature dependence of  $_{SH}^{ss}$ . From eq. (15),  $_{SH}^{ss}$  is proportional to 1=  $_{\rm f}$  when  $_{\rm f}$  0. Since  $_{\rm f}$  / ln (T=W<sub>band</sub>) for T T<sub>K</sub> [18],  $_{SH}^{ss}$  decreases as the temperature decreases. In contrast,  $_{SH}^{ss}$  /  $^{\rm f}$  for  $_{\rm f}$  0, which increases at low temperatures if  $_{0}$  is constant.

## 3.3. Side Jump Term

In this section, we brie y discuss the side jump term  $_{SH}^{sj}$ . In the T-matrix approximation,  $_{SH}^{sj}$  is given by [15]

$${}^{sj}_{SH} = \frac{e}{2} \frac{1}{N^2} \sum_{k,k^0 = 0}^{X} \frac{e J_k^{I} J_k^{R} O}{e k_x} \frac{e J_k^{I} J_k^{R} O}{e k_y} J_k^{R} (0) J_j^{I}$$

$${}^{h}_{T_k J_k^{R} O} G_{k^0}^{R} (0) + hR \$ Aij; \qquad (17)$$

whose diagramm atic expression is shown in Fig. 3. In contrast to the skew scattering



Figure 3. Diagrammatic expression for the side jump term in the T-matrix approximation. Both two diagrams give the same contribution. Note that  $J_{\rm d}$  is not necessary for the side jump.

term,  $J_d$  is not necessary for the side jump term. As reported in ref. [21], the large anom alous velocity  $v_{kM}^a$ , which is not perpendicular to the Ferm i surface, arises from the k-derivative of the phase factor in the c-f m ixing potential as follows:

$$\frac{@V_{kM}^{r}}{@k_{x}} 3 v_{kM}^{a} = iM \frac{1}{2} \frac{k_{y}}{k_{x}^{2} + k_{y}^{2}} V_{kM}^{f} :$$
(18)

The nalexpression for the side jump term in the T-matrix approximation is given by

$$_{\rm SH}^{\rm sj} = \frac{e}{2} \frac{4}{3} \frac{k_{\rm F}}{4} - \frac{f}{4};$$
 (19)

where we have used the relations  ${}^{P}_{M}$  M  $\dot{y}_{kM}^{f}$   $\dot{j} = 3\dot{y}_{f}\dot{j}(1 \sin^{2} )$  and  ${}^{P}_{M}$   ${}^{2}\dot{y}_{kM}^{f}$   $\dot{j} = 6\dot{y}_{f}\dot{j}$ . By using eqs. (15) and (19), the ratio  ${}^{sj}_{SH} = {}^{ss}_{SH}$  is given by  $\frac{28}{3} \frac{2}{J_{d}n}$ . Therefore,  ${}^{sj}_{SH}$  will exceed  ${}^{ss}_{SH}$  in dirty metals. However, the skew scattering contribution will be dominant in simple metals with magnetic in purities for  $n_{imp} < 0.01$  ( $_{0} < 10$  cm) [16].

#### 4. D iscussions

#### 4.1. Origin of the Skew Scattering Mechanism

In section 3.2, we have studied the SHC due to skew scattering by using the G reen function method. In this section, we discuss the origin of the skew scattering mechanism based on the Boltzmann transport theory. For this purpose, we study a simpli ed two-orbital model with M =  $\frac{5=2}{4}$ , assuming the strong crystalline electric eld. In this model,  $V_{kM}^{f} = \frac{4}{4} = 7V_{f} \frac{6}{6}Y_{3}^{3}$  (k) M;  $_{5=2} + Y_{3}^{2}$  (k) M;  $_{5=2}$ . Since  $V_{kM}^{f}$  /  $Y_{3}^{3}$  ( $\hat{k}$ ) / e  $^{3i}$   $^{k}$  approximately, the second order term of T  $^{f}$  is simply given as  $T^{f(2)R}$  iN (0) $e^{3i} (k k^{0})$ . In the Boltzm and transport theory, the spin Hall resistivity due to skew scattering is  ${}_{SH}^{ss} / {}_{Rx}k_{y}^{0}w$  (k ! k<sup>0</sup>), where w represents the scattering probability, which is proportional to  $n_{inp} = T_{k,k^0}^{f(2)R} + J_{k,k^0}^d$ due to Ferm i's golden rule in the present model. A coording to ref. [16], skew scattering occurs when the scattering probability includes an assymmetric component  $w^{ss}$  (k ! k<sup>0</sup>) / Im  $e^{i(k-k^0)}$  / (k  $\hat{k}^0$ )<sub>z</sub>. In the present model,  $w^{ss}$  arises from the interference of the f and d scattering channel, w  $^{ss}$  2  $T_{k}^{f\,(2)R}_{\,\,k^{\,0}}\,J_{k,k^{\,0}}^{\rm d}+c\kappa$  . In fact,  $w_{h}^{ss}(k \mid k^{0}) / \text{Im } e^{i(k k^{0})}$  in this model since  $J_{k,k^{0}}^{d}$  contains the term  $Y_2^{(2)}(\hat{k}) Y_2^{(2)}(\hat{k}^0) / e^{2i(k k^0)}$ . In summary, a conduction electron with hybridizes with  $l_z = 3$  state due to the strong SO I, and therefore the spin-dependent skew scattering probability  $w^{ss}(k ! k^0) / \text{Im } e^{i(k k^0)}$  arises from the interference of the f and d angular momenta. Thus, the origin of the SHE due to skew scattering mechanism is well understood based on the simplied two-orbital model.

## 4.2. Estimations of the Spin Hallangle and the Skew Scattering Term

First, we estimate the magnitude of the spin Hall angle tan  $_{SH}$   $\frac{\frac{S}{SH}}{\frac{2e}{xx}}\frac{2e}{h}$ . The longitudinal conductivity is given by  $_{xx} = \frac{e^2n}{2m}$ , where  $n = k_F^3 = 3^{-2}$  is the density of the conduction electrons. Then, the spin Hall angle is given by

$$\tan_{\rm H} = \frac{8^2}{7} J_{\rm d} N \ (0)^{-f} : \tag{20}$$

Since  $\tan_2 = N(0)J_{d}$  [18], eq. (20) can be rewritten as  $\tan_{SH} = \frac{8}{7} \frac{f}{2}$  if  $jJ_{d}N(0)$  1. In the case where  $f_{0}$ ,  $_{SH}$  reaches 0:3 for  $_{2}$  0:1 24]. Therefore, giant SHE will be realized in metals with rare-earth in purities.

Recently, giant SHE was observed in FePt/Au devices [23]. It was reported that the large spin Hall angle in Au is 0:1. Since the intrinsic SHE in Au is small due to the Ferm i surface being mainly composed of s-electrons [7], the observed giant SHE may be explained by the skew scattering mechanism. Very recently, the extrinsic SHE in AuFe metal has been studied with the rst-principles band structure calculations independently of our study [25].

Second, we estimate the magnitude of the skew scattering term for  $_2 = 0.1$ , where the spin Hallangle is 0.3. Then,  $_{SH}^{SS} = (h=2e)0.3$   $_{xx}$  from the above discussion. In the case where the resistivity is 10 cm, we obtain  $_{SH}^{SS} = 15000 (h=e)$   $^{1}$  cm  $^{1}$  if we put the length of unit cell a = 4A, which is the case for Pt and Au. The obtained skew scattering term is about 60 times larger than the SHC observed in Pt: 240 (h=e)  $^{1}$  cm  $^{1}$ . Since the resistivity in Pt and Au is 10 cm and 1 cm, respectively, the skew scattering term due to magnetic in purities should dom inate the intrinsic term. In contrast, the skew scattering due to \natural random ness" has not been observed in the AHE in transition metals, even in 10 cm 26]. Therefore, the orbital degrees of freedom of the in purity is indispensable for the giant extrinsic SHE.

Finally, we compare the magnitude of  ${}_{SH}^{ss}$  and  ${}_{SH}^{sj}$ . If we put  $k_F = =$  and  ${}_{f}$  in eq. (19),  ${}_{SH}^{sj} = \frac{e}{2a3} \frac{4}{a}$  (4=3)  ${}_{10}^{20}(h=e) {}^{1}$  cm  ${}^{1}$  for a = 4A. Therefore, the skew scattering term will be comparable in magnitude to the side jump term when

100 cm. Thus, the skew scattering term is dominant over the side jump term when 100 cm.

# 5. Sum m ary

In sum mary, we have studied the extrinsic SHE due to magnetic in purities, where Ce and Yb in purities have been discussed as a typical case. The obtained expression for the skew scattering term shows that the spin Hallangle reaches O (10<sup>-1</sup>), which is more than 10 times larger than that in Pt. Therefore, we propose that the extrinsic SHE due to rare-earth in purities is useful as a method for creating large spin current e ciently. The present study also suggests that the giant SHE will arise from other rare-earth atom s as well as 4d and 5d atom s that possesses strong SO I. As in the case for the intrinsic SHE, orbital degrees of freedom are essential for generating a huge extrinsic SHE. A coording to eq. (20), giant spin Hallangle always appears when f = 0. Thus, the K ondo resonance, N (0)J<sub>f</sub> = 1, is not a necessary condition for the giant SHE. In contrast, the AHC (=  $xy = H_z$ ) is enhanced by the K ondo e ect since it is proportional to the uniform susceptibility.

In a similar way to the present study, we can obtain  $S_{SH}^{SS}$  and  $S_{SH}^{Sj}$  for J = 7=2, which is the case for Y b-in purities. In this case,  $a_m^M = f(7=2+M)=7g^{1=2}m_M =_2$ ,

and  $_{f}$  is given by (4=3) times eq. (9). The obtained  $_{SH}^{ss}$  and  $_{SH}^{sj}$  are given by (3=4) times eq. (15) and eq. (19), respectively.

#### A cknow ledgem ents

W e are grateful to D.S.H irashim a and J.G oryo for fruitful discussions.

#### References

- [1] J. Sinova, D. Culcer, Q. Niu, N. A. Sinitsyn, T. Jungwirth, and A. H. MacDonald, Phys. Rev. Lett. 92 (2004) 126603.
- [2] S.Murakami, N.Nagaosa and S.C. Zhang, Phys. Rev. B 69 (2004) 235206.
- [3] E.Saitoh, M.Ueda, H.M. iya jim a and G.Tatara, Appl. Phys. Lett. 88 (2006) 182509.
- [4] T.Kimura, Y.Otani, T.Sato, S.Takahashi, and S.Maekawa, Phys. Rev. Lett. 98 (2007) 156601;
   L.Vila, T.Kimura, and Y.Otani, Phys. Rev. Lett. 99, 226604 (2007); Y.Otani et al., (unpublished)
- [5] H.Kontani, T.Tanaka, D.S.Hirashima, K.Yamada, and J.Inoue, Phys. Rev. Lett. 100, 096601 (2008).
- [6] H.Kontani, M.Naito, D.S.Hirashima, K.Yamada, and J.Inoue, J.Phys. Soc. Jpn. 76 103702 (2007).
- [7] T. Tanaka, H. Kontani, M. Naito, T. Naito, D. S. Hirashima, K. Yamada, and J. Inoue, Phys. Rev. B 77, 165117 (2008).
- [8] H.Kontani, T.Tanaka, D.S.Hirashim a, K.Yam ada, and J. Inoue, arX iv:0806.0210.
- [9] G.Y.Guo, S.Murakami, T.W. Chen, and N.Nagaosa, Phys. Rev. Lett. 100, 096401 (2008).
- [10] M.I.D yakonov and V.I.Perel, JETP Lett. 13 467 (1971).
- [11] J.E.Hirsch, Phys.Rev.Lett. 83, 1834 (1999).
- [12] S.Takahashiand S.M aekawa, J.Phys.Soc.Jpn.77, 031009 (2008).
- [13] J.Sm it, Physica 24 (1958) 39.
- [14] L.Berger, Phys. Rev. B 2 (1970) 4559.
- [15] A. Crepieux and P. Bruno, Phys. Rev. B 64 014416 (2001).
- [16] A.Fert, J.Phys.F 3, 2126 (1973), A.Fert and A.Friederich, Phys.Rev.B 13, 397 (1976).
- [17] A.Fert and O.Jaoul, Phys.Rev.Lett. 28, 303 (1972).
- [18] A.C.Hewson, The Kondo Problem to Heavy Fermions (Cambridge Studies in Magnetism, 1993);
   K.Yosida, Theory of Magnetism (Springer 1996).
- [19] We om it the atom ic SO I for d-electrons since it is much smaller than j  $E^{d}$  j.
- [20] K.Yam ada and K.Yosida: Prog.Theor.Phys.53 (1975) 970.
- [21] H.Kontaniand K.Yam ada, J.Phys.Soc.Jpn. 63, 2627 (1994).
- [22] F.D.M.Haldane, Phys. Rev. Lett. 40, 416 (1978).
- [23] T. Seki, Y. Hasegawa, S. Mitani, S. Takahashi, H. Imamura, S. Maekawa, J. Nitta, and K. Takanashi, Nature 7, 125 (2008).
- [24] Recently rst-principles band structure calculation has been performed by the present authors, and <sub>2</sub> is estimated as 0:1 for Y b impurities in Ag host.
- [25] G.Y.Guo, S.M aekawa, and N.Nagaosa, arX iv:0809.2921.
- [26] T.Miyasato, N.Abe, T.Fujii, A.Asamitsu, S.Onoda, Y.Onose, N.Nagaosa, and Y.Tokura, Phys. Rev. Lett. 99 (2007) 086602.